# PSMN9R3-60HS

N-channel 60 V, 9.3 mOhm, standard level MOSFET in LFPAK56D using TrenchMOS technology

26 September 2022

**Product data sheet** 

# 1. General description

Dual standard level N-channel MOSFET in an LFPAK56D (Dual Power-SO8) package using TrenchMOS technology.

### 2. Features and benefits

- Dual MOSFET
- Repetitive avalanche rated
- · High reliability LFPAK56D package
- Copper-clip, solder die attach
- Qualified to 175 °C

### 3. Applications

- Brushless DC motor control
- DC-to-DC converters
- · High-performance synchronous rectification
- · High performance and high efficiency server power supply

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
V <sub>DS</sub>	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 175 °C		-	-	60	V	
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>	[1]	-	-	40	Α	
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>		-	-	68	W	
T <sub>j</sub>	junction temperature			-55	-	175	°C	
Static characte	eristics FET1 and FET2					'	'	
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS}$ = 10 V; $I_D$ = 10 A; $T_j$ = 25 °C; Fig. 11		-	7.64	9.3	mΩ	
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 10 A; T <sub>j</sub> = 175 °C; Fig. 11; Fig. 12		-	17.1	20.8	mΩ	
Dynamic chara	cteristics FET1 and FE	T2		•				
$Q_{GD}$	gate-drain charge	I <sub>D</sub> = 10 A; V <sub>DS</sub> = 48 V; V <sub>GS</sub> = 10 V;		-	11	-	nC	
Q <sub>G(tot)</sub>	total gate charge	T <sub>j</sub> = 25 °C; <u>Fig. 13; Fig. 14</u>		-	34.2	-	nC	
Avalanche ruggedness FET1 and FET2								
E <sub>DS(AL)S</sub>	non-repetitive drain- source avalanche energy	$I_D$ = 40 A; $V_{sup} \le 60 \text{ V}$ ; $V_{GS}$ = 10 V; $T_{j(init)}$ = 25 °C; <u>Fig. 4</u>	[2] [3]	-	-	103	mJ	



Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Source-drain diode FET1 and FET2							
Q <sub>r</sub>		$I_S = 10 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V}; V_{DS} = 30 \text{ V}; T_j = 25 ^{\circ}\text{C}$		-	24	-	nC

- [1] Continuous current is limited by package.
- [2] Refer to application note AN10273 for further information
- [3] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C

# 5. Pinning information

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol	
1	S1	source1	8 7 6 5		
2	G1	gate1	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	D1 D1 D2 D2	
3	S2	source2			
4	G2	gate2			
5	D2	drain2			
6	D2	drain2			
7	D1	drain1	1 2 3 4	S1 G1 S2 G2	
8	D1	drain1	LFPAK56D; Dual LFPAK (SOT1205)	mbk725	

# 6. Ordering information

**Table 3. Ordering information** 

Type number	Package						
	Name	Description	Version				
PSMN9R3-60HS		plastic, single ended surface mounted package (LFPAK56D); 8 leads	SOT1205				

### 7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN9R3-60HS	9R3S60H

# 8. Limiting values

#### **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{DS}$	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 175 °C		-	60	V
$V_{DGR}$	drain-gate voltage	$R_{GS}$ = 20 k $\Omega$		-	60	V
$V_{GS}$	gate-source voltage	DC; T <sub>j</sub> ≤ 175 °C		-20	20	V
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>		-	68	W
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>	[1]	-	40	А
		V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 100 °C; <u>Fig. 2</u>	[1]	-	40	А

Symbol	Parameter	Conditions		Min	Max	Unit
I <sub>DM</sub>	peak drain current	pulsed; $t_p \le 10 \mu s$ ; $T_{mb} = 25 \text{ °C}$ ; Fig. 3		-	228	Α
T <sub>stg</sub>	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
Source-drain	n diode FET1 and FET2		'			
Is	source current	T <sub>mb</sub> = 25 °C	[1]	-	40	Α
I <sub>SM</sub>	peak source current	pulsed; $t_p \le 10 \mu s$ ; $T_{mb} = 25 °C$		-	228	Α
Avalanche ru	uggedness FET1 and FET2					
E <sub>DS(AL)S</sub>	non-repetitive drain- source avalanche energy	$I_D = 40 \text{ A}; V_{sup} \le 60 \text{ V}; V_{GS} = 10 \text{ V};$ $T_{j(init)} = 25 \text{ °C}; Fig. 4$	[2] [3]	-	103	mJ

- [1] Continuous current is limited by package.
- [2] Refer to application note AN10273 for further information
- [3] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C

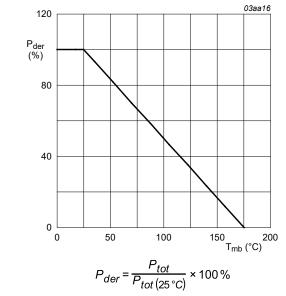
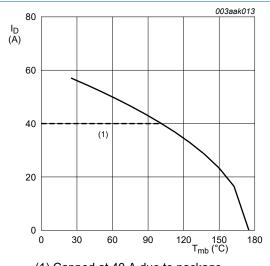


Fig. 1. Normalized total power dissipation as a function of mounting base temperature



(1) Capped at 40 A due to package  $V_{GS} \ge 10 \text{ V}$ 

Fig. 2. Continuous drain current as a function of mounting base temperature

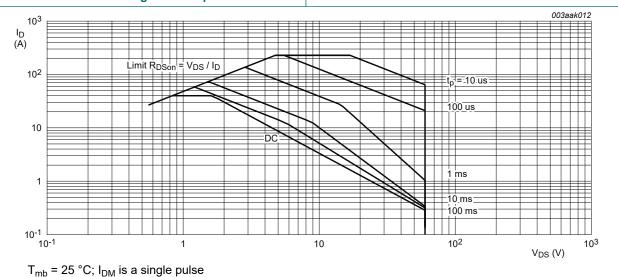
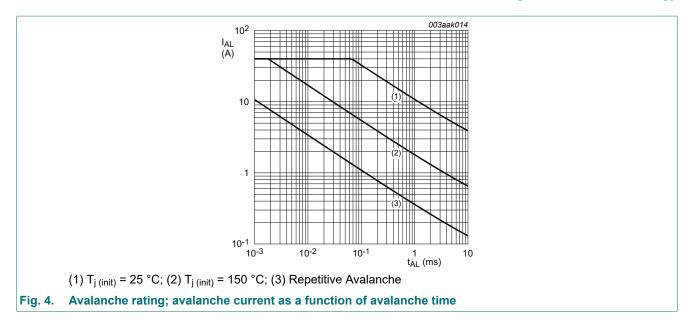


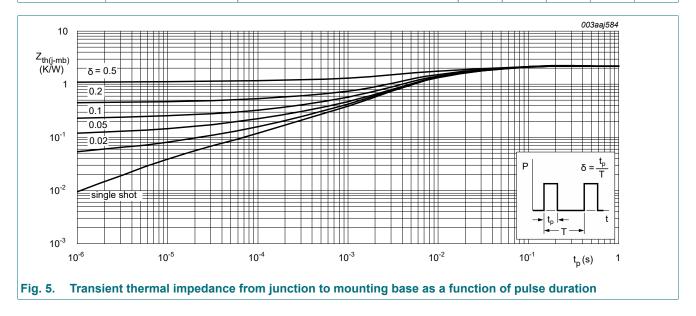
Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage



### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	Fig. 5	-	-	2.21	K/W
$R_{th(j-a)}$		Minimum footprint; mounted on a printed circuit board	-	95	-	K/W



### 10. Characteristics

#### **Table 7. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics FET1 and FET2					
V <sub>(BR)DSS</sub>	drain-source	I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = -55 °C	54	-	-	V
	breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	60	-	-	V
V <sub>GS(th)</sub>	gate-source threshold voltage	$I_D$ = 1 mA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 25 °C; <u>Fig. 9</u> ; <u>Fig. 10</u>	2.4	3	4	V
		$I_D$ = 1 mA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 175 °C; <u>Fig. 9</u> ; <u>Fig. 10</u>	1	-	-	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C}; Fig. 9;$ Fig. 10	-	-	4.5	V
loss	drain leakage current	V <sub>DS</sub> = 60 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	0.02	1	μΑ
		V <sub>DS</sub> = 60 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 175 °C	-	-	500	μΑ
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = -20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	2	100	nA
		V <sub>GS</sub> = 20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	2	100	nA
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS}$ = 10 V; $I_D$ = 10 A; $T_j$ = 25 °C; Fig. 11	-	7.64	9.3	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 10 A; T <sub>j</sub> = 175 °C; Fig. 11; Fig. 12	-	17.1	20.8	mΩ
Dynamic ch	naracteristics FET1 and FE	T2				
Q <sub>G(tot)</sub>	total gate charge	I <sub>D</sub> = 10 A; V <sub>DS</sub> = 48 V; V <sub>GS</sub> = 10 V;	-	34.2	-	nC
Q <sub>GS</sub>	gate-source charge		-	6.7	-	nC
$Q_{GD}$	gate-drain charge	1	-	11	-	nC
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = 25 V; V <sub>GS</sub> = 0 V; f = 1 MHz;	-	1761	2348	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C; <u>Fig. 15</u>	-	247	297	pF
C <sub>rss</sub>	reverse transfer capacitance		-	155	213	pF
d(on)	turn-on delay time	$V_{DS} = 48 \text{ V}; R_L = 5 \Omega; V_{GS} = 10 \text{ V};$	-	9.1	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 ^{\circ}C$	-	12.5	-	ns
d(off)	turn-off delay time	1	-	23	-	ns
f	fall time	1	-	15	-	ns
Source-dra	in diode FET1 and FET2		'	'		
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = 10 A; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C; <u>Fig. 16</u>	-	0.78	1.2	V
t <sub>rr</sub>	reverse recovery time	$I_S = 10 \text{ A}$ ; $dI_S/dt = -100 \text{ A/}\mu\text{s}$ ; $V_{GS} = 0 \text{ V}$ ;	-	25	-	ns
Q <sub>r</sub>	recovered charge	$V_{DS} = 30 \text{ V}; T_j = 25 \text{ °C}$	-	24	-	nC

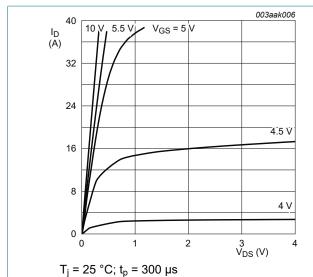


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values

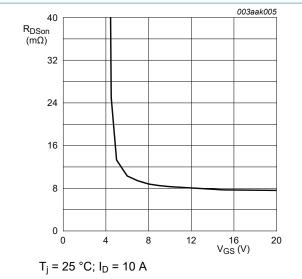


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

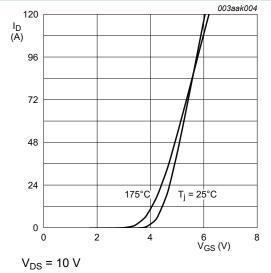


Fig. 8. Transfer characteristics; drain current as a function of gate-source voltage; typical values

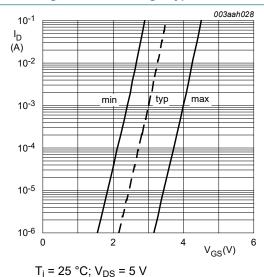


Fig. 9. Sub-threshold drain current as a function of gate-source voltage

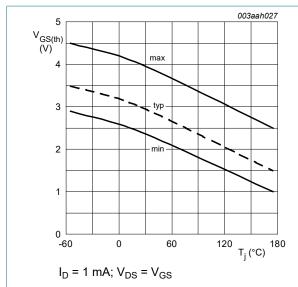


Fig. 10. Gate-source threshold voltage as a function of junction temperature

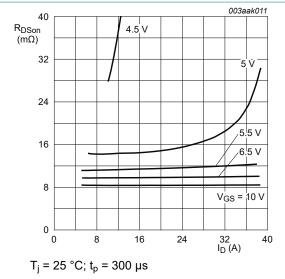


Fig. 11. Drain-source on-state resistance as a function of drain current; typical values

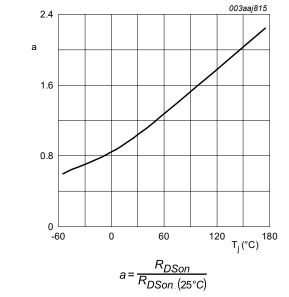


Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

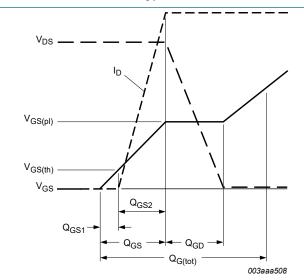


Fig. 13. Gate charge waveform definitions

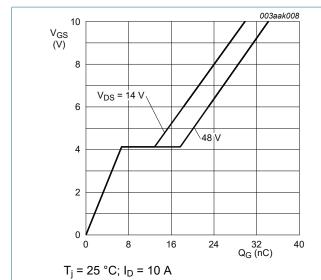


Fig. 14. Gate-source voltage as a function of gate charge; typical values

 $V_{GS} = 0 V$ 

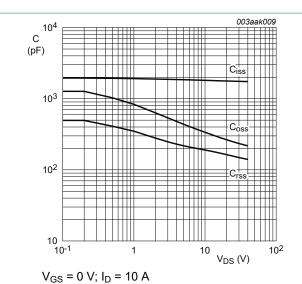


Fig. 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical

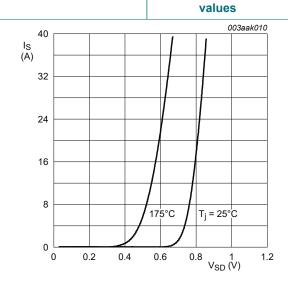
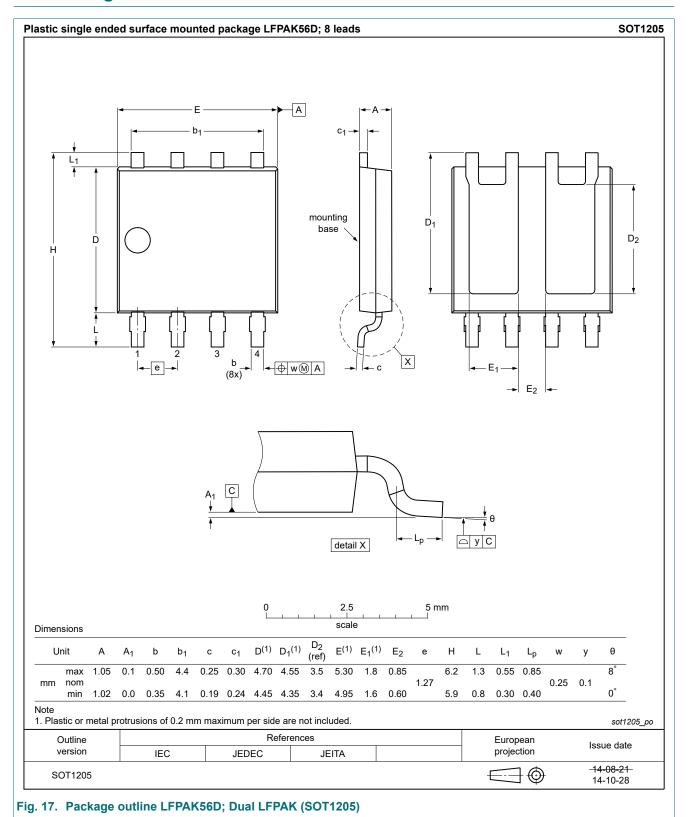


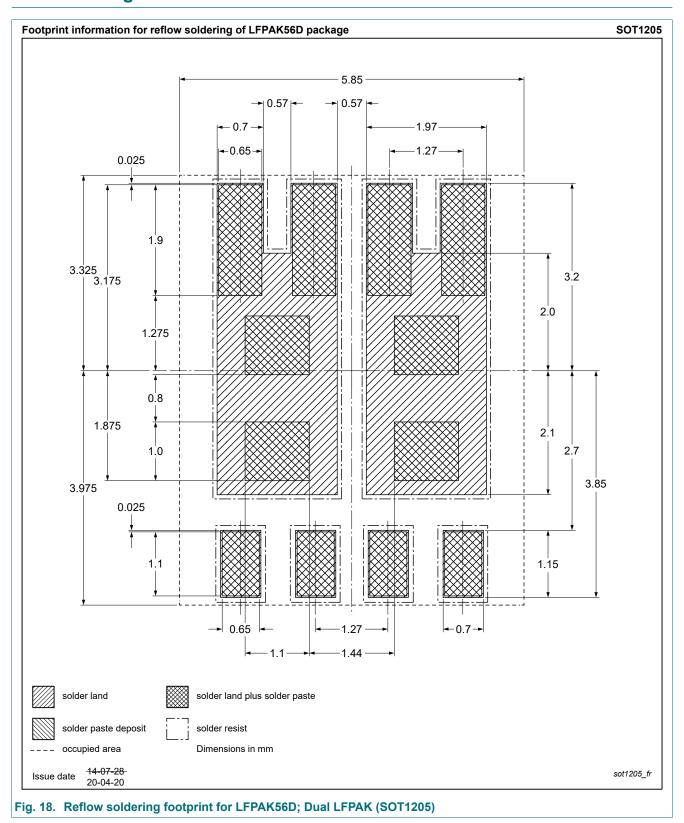
Fig. 16. Source (diode forward) current as a function of source-drain (diode forward) voltage; typical values

**Product data sheet** 

# 11. Package outline



# 12. Soldering



**Product data sheet** 

### 13. Legal information

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